TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC4248

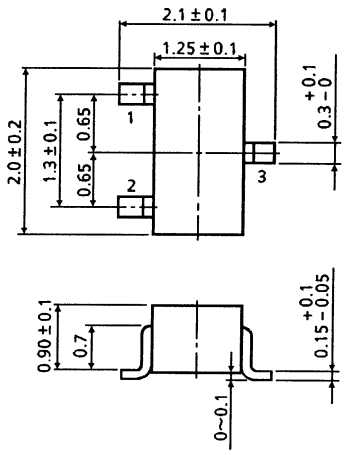
TV Tuner, UHF Oscillator Applications
(common collector)

- Transition frequency is high and dependent on current excellently.

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	20	V
Collector-emitter voltage	V_{CEO}	12	V
Emitter-base voltage	V_{EBO}	3	V
Base current	I_B	15	mA
Collector current	I_C	30	mA
Collector power dissipation	P_C	100	mW
Junction temperature	T_j	125	°C
Storage temperature range	T_{stg}	−55~125	°C

Unit: mm



1. BASE
2. EMITTER
3. COLLECTOR

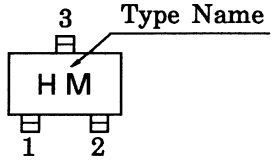
JEDEC	—
JEITA	SC-70
TOSHIBA	2-2E1A

Weight: 0.006 g (typ.)

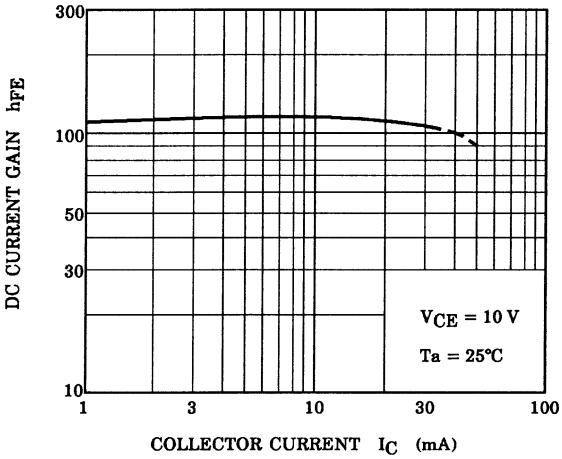
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	V_{CB} = 10 V, I_E = 0	—	—	0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB} = 2 V, I_C = 0	—	—	1.0	μA
Collector-emitter breakdown voltage	$V_{(BR)\ CEO}$	I_C = 1 mA, I_B = 0	12	—	—	V
DC current gain	h_{FE}	V_{CE} = 10 V, I_C = 5 mA	70	—	130	
Transition frequency	f_T	V_{CE} = 10 V, I_C = 10 mA	3	4	—	GHz
Output capacitance	C_{ob}	V_{CB} = 10 V, I_E = 0, f = 1 MHz	—	1.05	1.35	pF
Collector-base time constant	C_c.rbb'	V_{CB} = 10 V, I_C = 5 mA, f = 30 MHz	—	4.5	9.0	ps

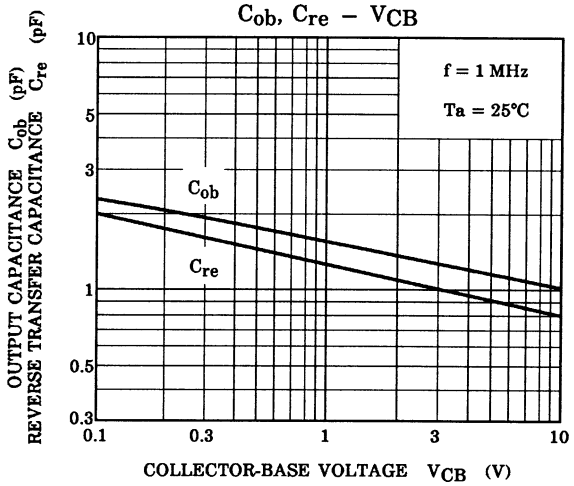
Marking



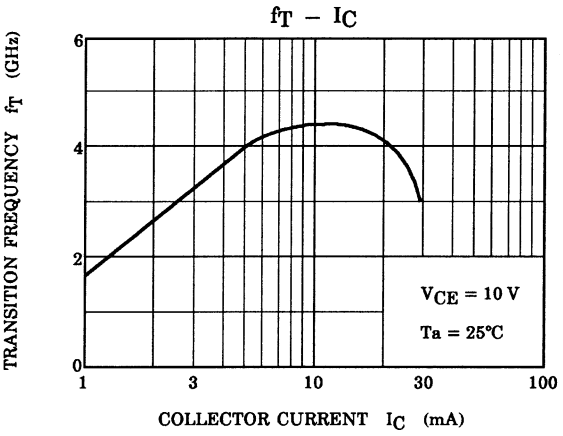
h_{FE} – I_C



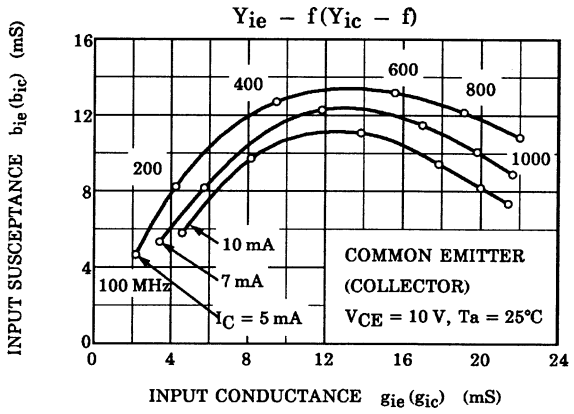
C_{ob}, C_{re} – V_{CB}



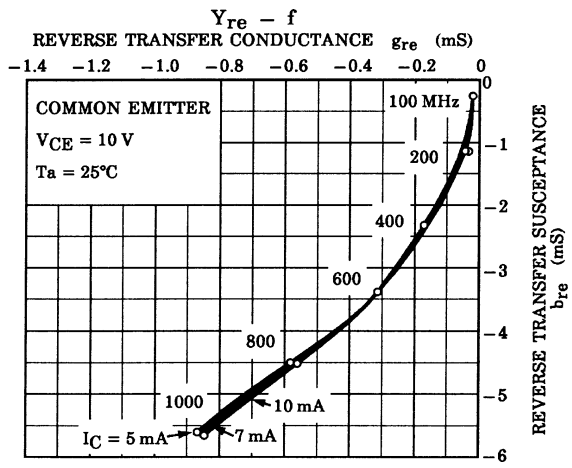
f_T – I_C



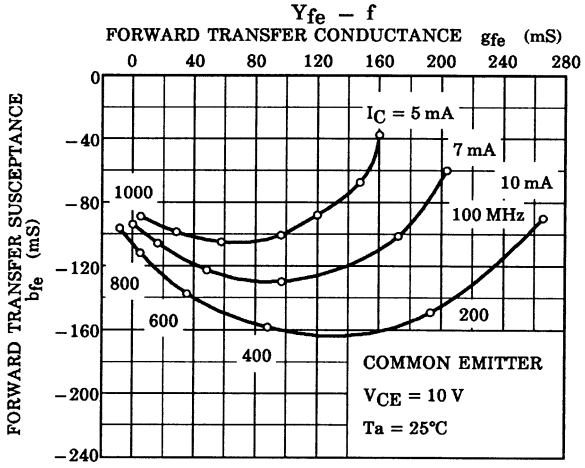
Y_{ie} – f(Y_{ic} – f)



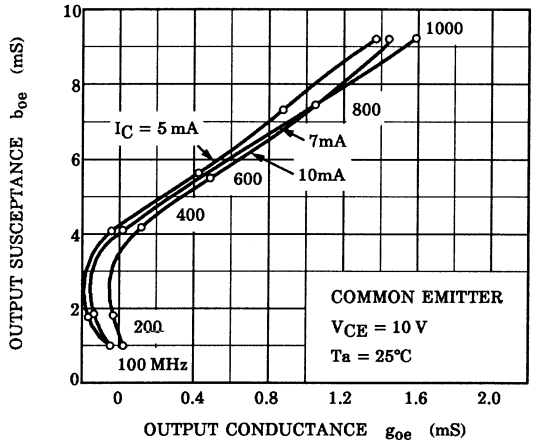
Y_{re} – f



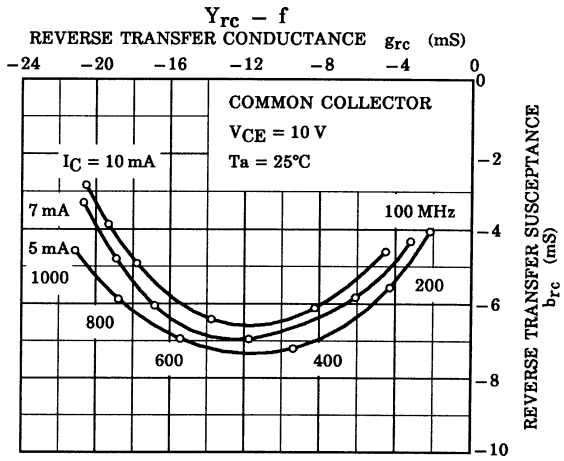
Y_{fe} – f



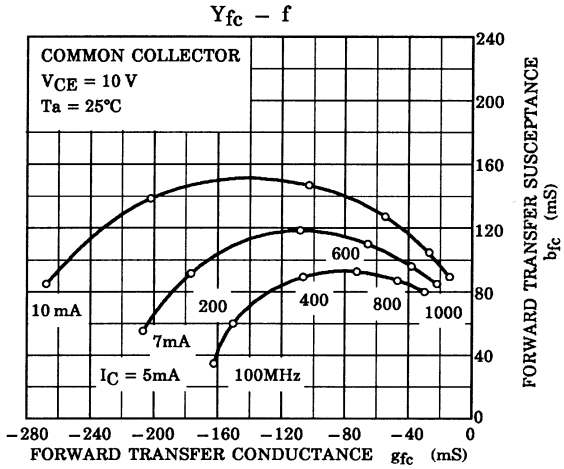
Y_{oe} – f



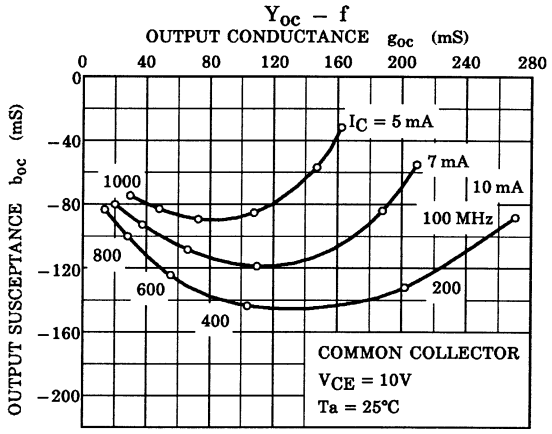
Y_{rc} – f



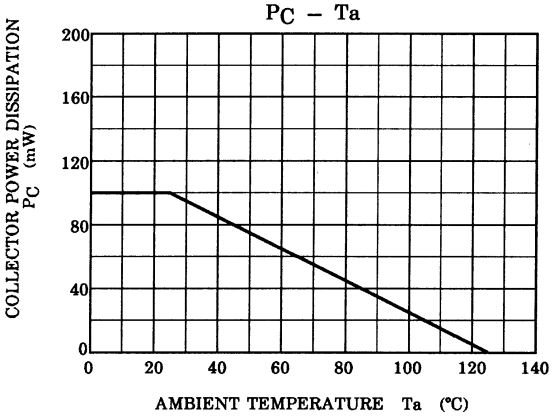
Y_{fc} – f



Y_{oc} – f



P_C – Ta



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